imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





STTH1008DTI

800 V tandem hyperfast diode

Datasheet – production data



- High voltage rectifier
- Tandem diodes in series
- Very low switching losses
- Insulated device with internal ceramic
- Equal thermal conditions for both 400 V diodes
- Static and dynamic equilibrium of internal diodes are warranted by design

Description

The STTH1008DTI is an ultrahigh performance diode composed of two 400 V dice in series.

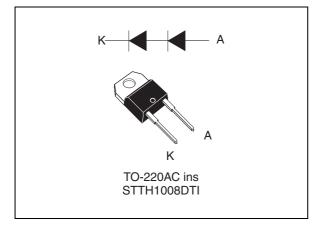


Table 1. Device summary

I _{F(AV)}	10 A
I _{FRM}	20 A
V _{RRM}	800 V
t _{rr}	40 ns
I _{RM}	8.5 A
V _F	1.7 V
Tj	150 °C

This is information on a product in full production.

1 Characteristics

Table 2. Absolute ratings (limiting values per diode at 25 °C, unless otherwise specified)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	800	V	
I _{F(RMS)}	Forward rms current	16	А	
I _{F(AV)}	Average forward current, $\delta = 0.5$	10	А	
I _{FRM}	Repetitive peak forward current $T_c = 135 \text{ °C}, \delta = 0.3$		20	А
I _{FSM}	Surge non repetitive forward current	120	А	
T _{stg}	Storage temperature range	-65 to +175	°C	
Тj	Maximum junction temperature		150	°C

Table 3. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	2.5	°C/W

Table 4. Static electrical characteristics

Symbol	Parameters	Test conditions		Min.	Тур	Max.	Unit
I _B ⁽¹⁾	Povorco lookago ourront	T _j = 25 °C	V _ V			20	
'R` ´	I _R ⁽¹⁾ Reverse leakage current	T _j = 150 °C	· V _R = V _{RRM}		20	200	μA
		T _c = 25 °C			2.15	2.5	
V _F ⁽²⁾	Forward voltage drop	T _c = 150 °C			1.7	2.05	V
۷F	VE V I Olward Voltage drop	T _c = 25 °C	I _F = 20 A		2.45	2.85	v
		T _c = 150 °C	1F = 20 A		2.05	2.45	

1. Pulse test: $t_{\scriptscriptstyle P}$ = 5 ms, δ < 2%

2. Pulse test: t_P = 380 µs, δ < 2%

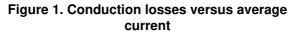
To evaluate the conduction losses use the following equation:

 $P = 1.65 \text{ x } I_{F(AV)} + 0.04 \text{ x } {I_{F}}^{2}_{(RMS)}$



Symbol	Parameters	1	Test conditions	Min.	Тур	Max.	Unit
I _{RM}	Reverse recovery current	$T_j = 125 \text{ °C}$ $I_F = 10 \text{ A}, V_R = 400 \text{ V}, \\ dI_F/dt = -200 \text{ A}/\mu\text{s}$			8.5	11.5	A
S _{factor}	Softness factor	- ,	$dI_F/dl = -200 \text{ A}/\mu\text{s}$		0.8		
+	Reverse recovery time		$I_F = 1 \text{ A}, V_R = 30 \text{ V}, \\ dI_F/dt = -50 \text{ A}/\mu\text{s}$		40	55	ns
t _{rr}	neverse recovery line	$T_{j} = 125 \text{ °C} \qquad \begin{matrix} I_{F} = 10 \text{ A}, V_{R} = 400 \text{ V}, \\ dI_{F}/dt = -200 \text{ A}/\mu\text{s} \end{matrix}$			80		115
t _{fr}	Forward recovery time	T _j = 25 °C	I _F = 10 A, V _{FB} = 3 V,			180	ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	$dI_F = 10 \text{ A}, V_{FR} = 3 \text{ V},$ $dI_F/dt = 100 \text{ A}/\mu\text{s}$		4.5	7	V

ics



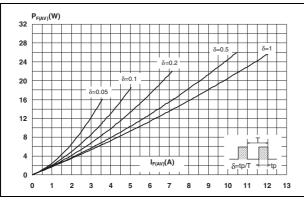
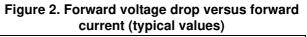
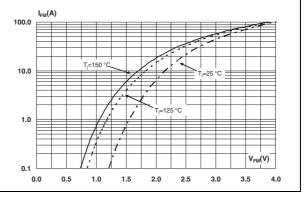
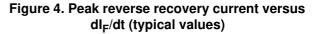


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration







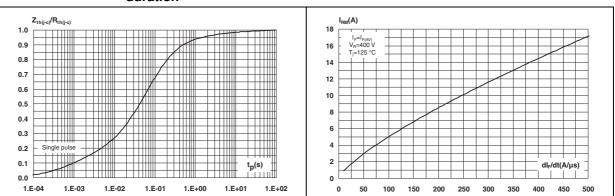


Figure 5. Reverse recovery time versus dI_F/dt (typical values)

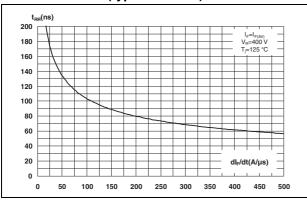


Figure 7. Reverse recovery softness factor versus dl_F/dt (typical values)

SFACTOR 1.4 I, Vp=400 V 1.2 =125 °C 1.0 0.8 0.6 0.4 0.2 dl_⊧/dt(A/µs) 0.0 0 50 100 150 200 250 300 350 400 450 500

Figure 6. Reverse recovery charges versus dl_F/dt (typical values)

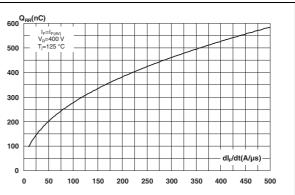


Figure 8. Relative variations of dynamic parameters versus junction temperature

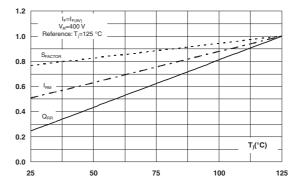
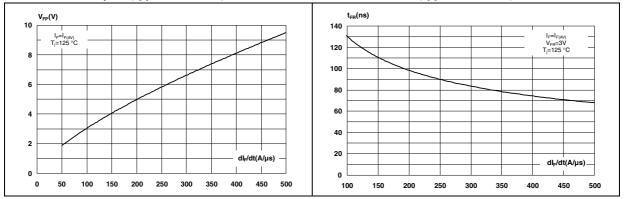


Figure 9. Transient peak forward voltage versus Figure 10. Forward recovery time versus dl_F/dt dl_F/dt (typical values)

(typical values)





i igai e i i ealiettell eap			
C(pF))		
100		F=	1 MHz
		Vosc=	:30 mV _{RMS} = =25 °C −
			-+-+++++
10			
1			V _R (V)
1	10	100	1000

Figure 11. Junction capacitance versus reverse voltage applied (typical values)



2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK[®] is an ST trademark.

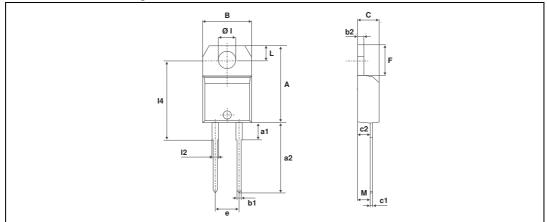


Figure 12. TO-220AC ins dimension definitions



	Dimensions							
Ref.		Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.		
А	15.20		15.90	0.598		0.625		
a1		3.75			0.147			
a2	13.00		14.00	0.511		0.551		
В	10.00		10.40	0.393		0.409		
b1	0.61		0.88	0.024		0.034		
b2	1.23		1.32	0.048		0.051		
С	4.40		4.60	0.173		0.181		
c1	0.49		0.70	0.019		0.027		
c2	2.40		2.72	0.094		0.107		
е	4.80		5.40	0.189		0.212		
F	6.20		6.60	0.244		0.259		
ØI	3.75		3.85	0.147		0.151		
14	15.80	16.40	16.80	0.622	0.646	0.661		
L	2.65		2.95	0.104		0.116		
12	1.14		1.70	0.044		0.066		
М		2.60			0.102			

Table 6. TO-220AC ins dimension values



3 Ordering information

Table	7.	Ordering	information
-------	----	----------	-------------

Ordering code	Marking	Package	Weight	Base qty	Delivery mode
STTH1008DTI	STTH1008DTI	TO-220AC insulated	2.3 g	50	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
05-Mar-2013	1	Initial release.



Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

ST PRODUCTS ARE NOT AUTHORIZED FOR USE IN WEAPONS. NOR ARE ST PRODUCTS DESIGNED OR AUTHORIZED FOR USE IN: (A) SAFETY CRITICAL APPLICATIONS SUCH AS LIFE SUPPORTING, ACTIVE IMPLANTED DEVICES OR SYSTEMS WITH PRODUCT FUNCTIONAL SAFETY REQUIREMENTS; (B) AERONAUTIC APPLICATIONS; (C) AUTOMOTIVE APPLICATIONS OR ENVIRONMENTS, AND/OR (D) AEROSPACE APPLICATIONS OR ENVIRONMENTS. WHERE ST PRODUCTS ARE NOT DESIGNED FOR SUCH USE, THE PURCHASER SHALL USE PRODUCTS AT PURCHASER'S SOLE RISK, EVEN IF ST HAS BEEN INFORMED IN WRITING OF SUCH USAGE, UNLESS A PRODUCT IS EXPRESSLY DESIGNATED BY ST AS BEING INTENDED FOR "AUTOMOTIVE, AUTOMOTIVE SAFETY OR MEDICAL" INDUSTRY DOMAINS ACCORDING TO ST PRODUCT DESIGN SPECIFICATIONS. PRODUCTS FORMALLY ESCC, QML OR JAN QUALIFIED ARE DEEMED SUITABLE FOR USE IN AEROSPACE BY THE CORRESPONDING GOVERNMENTAL AGENCY.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries. Information in this document supersedes and replaces all information previously supplied. The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2013 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com



DocID023113 Rev 1